NSN 5961-01-131-9800

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-131-9800 **Inclosure Material:** Glass **Overall Length:** Between 0.145 inches and 0.165 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.068 inches and 0.075 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 reverse voltage, peak and 50.0 breakdown voltage, dc **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 1.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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